



ATTORNEY DOCKET NO. 041501.541

RECEIVED  
PATENT  
TECHNOLOGY CENTER 2800  
OCT 03 2002

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
 )  
Won Jun LEE )  
 )  
Application No.: 09/717,399 )  
 )  
Filed: November 22, 2000 )  
 )  
For: METAL THIN FILM OF )  
SEMICONDUCTOR DEVICE AND )  
METHOD OF FORMING THE SAME )

Group Art Unit: 2814

Examiner: V. Trinh

#9A Andt  
M. Brunson  
7/22/03

Commissioner for Patents  
Washington, D.C. 20231

Sir:

AMENDMENT

In response to the Office Action dated July 3, 2002 (Paper No. 8), the period for response to which extends through October 3, 2002, please amend the above-referenced application as follows:

IN THE DRAWINGS:

Applicant requests approval of the proposed new drawings provided with a Request for Approval of New Drawings filed concurrently herewith. Applicant respectfully submits that the new drawings do not introduce new matter, and are provided in accordance with the Examiner's suggestions.

IN THE SPECIFICATION:

Please replace the paragraph beginning on page 9, line 2 with the following:

--A metal thin film according to the present invention includes a barrier metal layer 52

formed on a semiconductor substrate 51 including an interleaving insulating film 57, and a PVD

1